

Tris(trimethylsilyl)sulfonium and Methylbis(trimethylsilyl)sulfonium Ions: Preparation, NMR Spectroscopy, and Theoretical Studies¹

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Tris(trimethylsilyl)sulfonium **1** and methylbis(trimethylsilyl)sulfonium **2** ions were prepared as long-lived species by reacting trimethylsilane and trityl tetrakis(pentafluorophenyl)borate (Ph₃C⁺TPFPB) in the presence of precursor sulfides and characterized by ¹H, ¹³C, and ²⁹Si NMR spectroscopy at –78 °C. Attempted preparation of dimethyl(trimethylsilyl)sulfonium ion under similar conditions failed as a result of the formation of the more stabilized trimethylsulfonium ion. Structures, and ¹³C and ²⁹Si NMR chemical shifts were calculated by density functional theory (DFT)/IGLO methods. The calculated results agree well with the experimental data.

Introduction

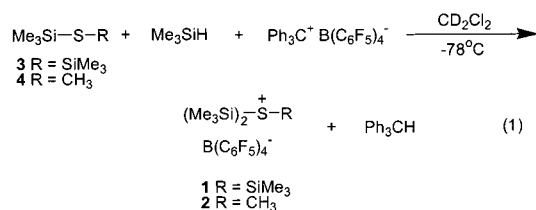
Sulfonium salts containing a tricoordinated sulfur atom attached to three carbon atoms have been well-known since the early 1900s. Trialkylsulfonium ions are more stable than the corresponding trialkyloxonium ions and can be easily prepared by the alkylation of saturated dialkyl sulfides under mild conditions because of sufficient nucleophilicity of the sulfur atom.² Sulfonium salts and the ylides derived from them have become increasingly useful in organic synthesis,³ and more recently sulfonium ions have found specific industrial applications as cationic initiators for polymerization.⁴ Although there has been increasing interest in the chemistry of heterosulfonium salts in which one or more of the ligand is a heteroatom (halogen, sulfur, oxygen, or nitrogen), silyl-substituted sulfonium ions are rare and their structures have not been confirmed.⁵

Hydride transfer of organohydrosilane to trityl cations, known as Corey hydride transfer,⁶ has been well adopted for the production of silyl cation⁷ and synthesis of silylated onium ions.⁸ We previously reported the preparation and NMR spectroscopic characterization of long-

lived trisilyloxonium ions.^{8c} In our continuing studies of silyl-substituted onium ions,^{8a–c} we now wish to report the preparation and NMR (¹H, ¹³C, ²⁹Si) spectroscopic characterization of long-lived trisilylsulfonium and methyldisilylsulfonium ions. We have also calculated the structure of the sulfonium ions using density functional theory (DFT) method. ¹³C and ²⁹Si NMR chemical shifts of the ions were also computed using the IGLO method, and the results were compared with the experimental data.

Results and Discussion

Synthesis of Trisilylsulfonium Ion and NMR Studies. In contrast to studies on trisilyloxonium ion reported by Olah and Prakash,^{8c} when the hydride abstraction from trimethylsilane by trityl TFPB was carried out in the presence of 3–5 equiv of hexamethyldisilathiane **3** at –78 °C, trisilylsulfonium was not formed. In a separate experiment, it was shown that hexamethyldisilathiane undergoes fast exchange with trityl TFPB in CD₂Cl₂ even at –78 °C, as shown by ¹H, ¹³C, and ²⁹Si NMR. To avoid this exchange, hexamethyldisilathiane and trityl TFPB were used in equimolar amount, so that all hexamethyldisilathiane could react with the in-situ-generated trimethylsilyl cation. Thus when trityl TFPB in CD₂Cl₂ solution was added to a mixture of trimethylsilane and 1 equiv of hexamethyldisilathiane at –78 °C under argon in a NMR tube, successful formation of tris(trimethylsilyl)sulfonium ion **1** was observed (eq 1).



¹H NMR spectrum recorded at –78 °C shows a peak at δ 0.75 corresponding to the methyl groups of trisilyl-

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(2) Olah, G. A.; Laali, K. K.; Wang, Q.; Prakash, G. K. S. *Onium Ions*; John Wiley & Sons: New York, 1998.

(3) Stirling, C. J. M., Ed. *The Chemistry of Sulphonium Group*. In *The Chemistry of Functional Groups*; Patai, S., Series Ed.; Wiley: New York, 1981; Parts 1 and 2.

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(5) Although there have been two reports on the preparation of silylsulfonium ions, the claims are not true; see refs 10 and 11.

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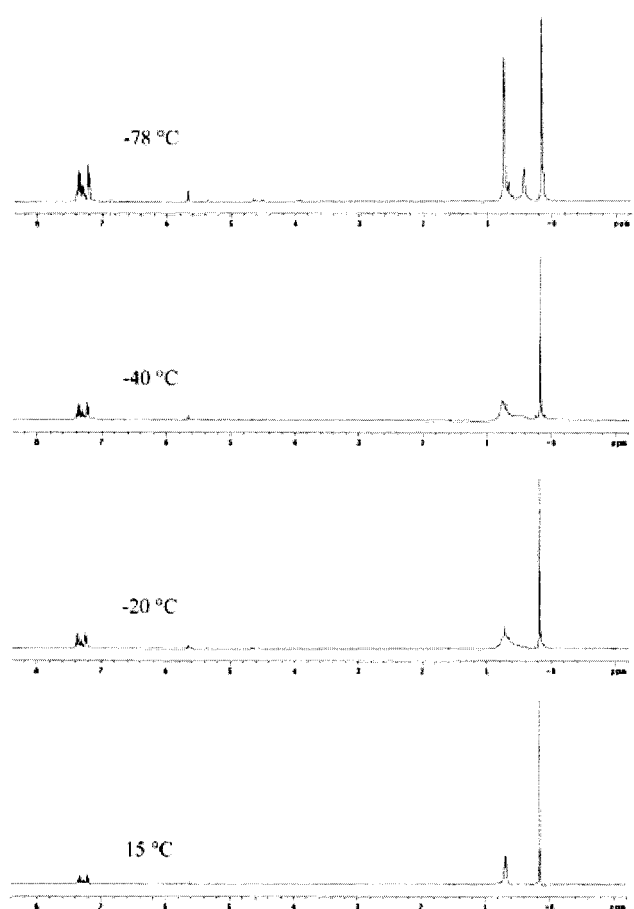
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(8) (a) Olah, G. A.; Rasul, G.; Prakash, G. K. S. *J. Organomet. Chem.* **1996**, *521*, 271. (b) Prakash, G. K. S.; Wang, Q.; Rasul, G.; Olah, G. A. *J. Organomet. Chem.* **1998**, *550*, 119. (c) Olah, G. A.; Li, X.-Y.; Wang, Q.; Rasul, G.; Prakash, G. K. S. *J. Am. Chem. Soc.* **1995**, *117*, 8962. (d) Kira, M.; Hino, T.; Sakurai, H. *J. Am. Chem. Soc.* **1992**, *114*, 6697.

Table 1. NMR Chemical Shifts of Some Silylsulfonium Ions and Their Precursors^a

compounds	¹ H (SiCH ₃) ppm		¹³ C (SiCH ₃) ppm		²⁹ Si ppm	
	exp	exp	calcd	exp	calcd	
Me ₃ SiH	0.11	-2.6	-2.2	-16.3	-16.3	
(Me ₃ Si) ₂ S (3)	0.33	4.1	3.7	12.9	15.3	
(Me ₃ Si) ₃ S ⁺ (1)	0.75	2.9	3.0	38.8	42.9	
Me ₃ SiSCH ₃ (4)	0.30	0.3	0.3	15.9	16.0	
(Me ₃ Si) ₂ S ⁺ CH ₃ (2)	0.68	-0.2	-0.3	40.8	46.8	

^a Experimental and calculated chemical shifts are referenced to TMS.

**Figure 1.** ¹H NMR spectra of (Me₃Si)₃S⁺ at variable temperatures.

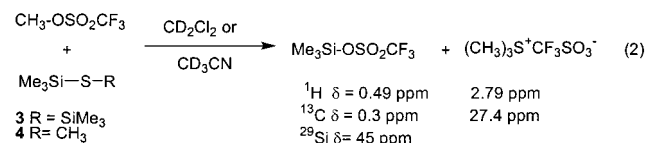
sulfonium ion. ¹³C and ²⁹Si NMR resonances for the trisilylsulfonium ion appeared at 2.9 and 38.8 ppm, respectively (see Table 1). The ²⁹Si NMR shift of **1** is deshielded by 26 ppm compared to that of hexamethyldisilathiane (²⁹Si δ 13). Even though the chemical shifts cannot be directly related to positive charge density, the results qualitatively indicate that the positive charge of the trisilylsulfonium ion is delocalized on both S and Si atoms. To examine the stability of **1** in the solution, we further recorded the NMR spectra of the trisilylsulfonium ion reaction mixture did not change below -60 °C. However, the signals of **1** and a small amount of remaining hexamethyldisilathiane coalesced on raising the temperature above -60 °C (Figure 1). This exchange was clearly indicated by the observed averaged peaks in ¹H, ¹³C, and ²⁹Si NMR at room temperature; the resonances were 0.68, 3.4, and 8.7 ppm, respectively. It

is interesting to note that this exchange process is thermally reversible, and a sharp singlet resonance at δ 38.8 was obtained in the ²⁹Si NMR spectrum upon cooling the solution back to -78 °C.

We treated trimethylsilyl trifluoromethanesulfonate (TMSOTf) with hexamethyldisilathiane in CD₂Cl₂ to study the effect of other low nucleophilicity counteranions. However, we observed only the starting materials by ¹H, ¹³C, and ²⁹Si NMR with no evidence for the formation of trisilylsulfonium ion. This result can be explained by the strength of the stronger Si-O bond in TMSOTf compared to the Si-S bond in **1**.

Synthesis of Methylsilylsulfonium Ion and NMR Studies. Similarly, methylthiotrimethylsilane **4** and trimethylsilane in the presence of 1 equiv of trityl TFPFB formed the corresponding methylbis(trimethylsilyl)sulfonium ion **2**, whose NMR data are also shown in Table 1. A solution of ion **2** was found to be more stable than that of ion **1**, and ¹H, ¹³C, and ²⁹Si NMR chemical shifts of **2** did not show any temperature dependence up to room temperature. The ¹H NMR chemical shifts of **2** at δ 0.68 (Si-CH₃) and δ 2.37 (S-CH₃) were found deshielded compared to the progenitor, methylthiotrimethylsilane at δ 0.30 (Si-CH₃) and δ 2.02 (S-CH₃). The ¹³C NMR resonances at -0.2 (Si-CH₃) and 10.8 ppm (S-CH₃) also confirm the formation of **2**. ²⁹Si NMR chemical shift of **2** was found to be at 40.8 ppm.

Attempted preparation of **2** either by reacting methylthiotrimethylsilane and TMSOTf or by reacting hexamethyldisilathiane and methyl iodide did not proceed; only starting materials were observed in both cases. Independent reaction of hexamethyldisilathiane and methyl trifluoromethanesulfonate (MeOTf) in either CD₂Cl₂ or CD₃CN resulted in trimethylsulfonium triflate and TMSOTf quantitatively (eq 2). The products were identified by ¹H, ¹³C, and ²⁹Si NMR spectroscopy.



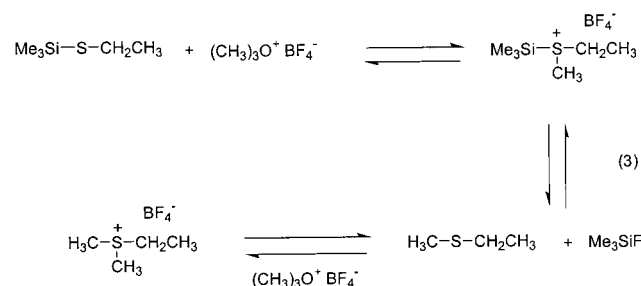
Attempted Synthesis of Dimethylsilylsulfonium Ion. When dimethyl sulfide was allowed to react with trimethylsilane in the presence of 1 equiv of trityl TFPFB in CD₂Cl₂ at -78 °C, we observed a white precipitate that was characterized as trimethylsulfonium ion and triphenylmethane by NMR spectroscopy. Even under a variety of conditions no evidence for the formation of dimethylsilylsulfonium ion was found. In CD₃CN solvent, in the above experiment at -40 °C, the NMR data showed only the formation of trimethylsulfonium ion (¹H δ 2.79, ¹³C δ 27.4 ppm) and triphenylmethane as well as few unidentified silyl compounds.

Attempts to prepare dimethylsilylsulfonium ion by reacting thiomethyltrimethylsilane **4** and MeOTf in either CD₂Cl₂ or CD₃CN also resulted in TMSOTf and trimethylsulfonium ion. The formation of trimethylsulfonium ion instead of dimethylsilylsulfonium ion is presumably due to displacement of the Me₃Si group in the initially formed dimethylsilylsulfonium ion to produce the more stable trimethylsulfonium ion.⁹ Since the sulfonium ions are known to disproportionate, the dimeth-

(9) Ray, F. E.; Levine, I. *J. Org. Chem.* **1937**, *2*, 267.

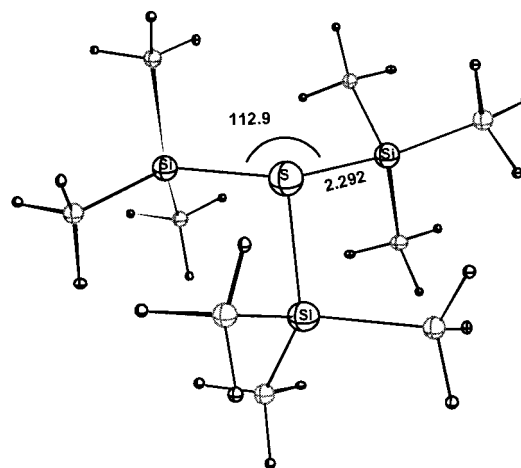
ylsilylsulfonium ion appears to desilylate and react with another molecule of MeOTf, giving trimethylsulfonium ion in all cases.

Abel et al. have claimed that a mixture of *n*-butylthio-trimethylsilane and methyl iodide upon standing in the dark for several days resulted in *n*-butylmethyl(trimethylsilyl)sulfonium iodide as a fine white precipitate.¹⁰ The evidence for the formation of silylsulfonium ion was based on poor elemental analysis data. We have repeated the work of Abel et al. by reacting methylthiotrimethylsilane and methyl iodide in either CD₂Cl₂ or CD₃CN. The precipitation did occur in both solvents after 2 days; however, no evidence for the formation of dimethylsilylsulfonium ion was obtained by ¹³C and ²⁹Si NMR spectroscopy. The white precipitate was found to be only the trimethylsulfonium ion (¹H δ 2.73, ¹³C δ 27.4). Recently Franek and El-Sayed reported the first preparation of dialkylsilylsulfonium ions by reacting ethyl- or propylthiotrimethylsilane and Meerwein's trimethyloxonium salt. The claim for the purported silylsulfonium ions was based on the ¹H NMR data.¹¹ Repetition of this work by treating ethylthiotrimethylsilane and trimethyloxonium tetrafluoroborate in CD₃NO₂ at -10 °C gave almost identical reported ¹H NMR resonances (δ 0.22, 1.50, 2.91, 3.34) with a product yield of 50%.¹² However, ¹H NMR integration and ¹³C NMR data (δ_{obs} 8.9, 24.7, 38.9) suggest that the observed species is actually ethyldimethylsulfonium tetrafluoroborate (eq 3). The presence

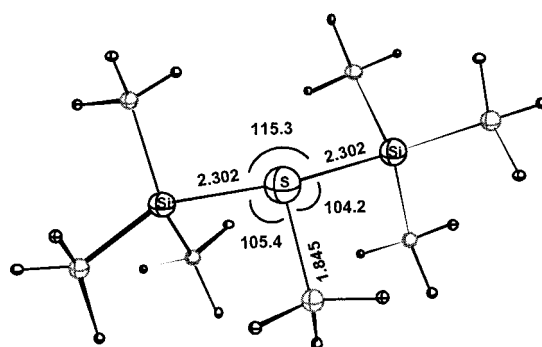


of trimethylfluorosilane¹³ was also confirmed by ²⁹Si and ¹⁹F NMR spectra (lit.¹⁴ ²⁹Si, δ 32.9 in acetone-*d*₆ relative to internal TMS, doublet, *J* = 274 Hz; ¹⁹F, δ -156 relative to internal CFCl₃). Trimethylfluorosilane is produced by the reaction of initially formed ethylmethyl(trimethylsilyl)sulfonium ion with the F⁻ ions of BF₄⁻ moiety. Since ethylthiotrimethylsilane requires 2 equiv of (CH₃)₃O⁺BF₄⁻ to form the ethyldimethylsulfonium ion (eq 3), when both reagents were mixed in 1:1 ratio, only half of the sulfide reacted. This result is consistent with the Franek and El-Sayed's work wherein roughly 56% yield of the product was observed.

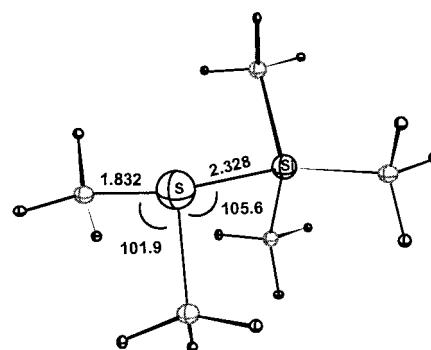
When a similar silylonium ion, trimethylsilylnitrilium tetrafluoroborate (Me₃SiNCCH₃⁺ BF₄⁻) was reported by Wenkert et al.,¹⁵ Bassindale refuted their claim,¹⁴ concluding that the reported preparation of silylnitrilium tetrafluoroborate actually gave trimethylfluorosilane and boron trifluoride coordinated acetonitrile complex.



[(CH₃)₃Si]₃S⁺ 1 (C₃)



[(CH₃)₃Si]₂S⁺CH₃ 2 (C₁)



(CH₃)₃SiS⁺(CH₃)₂ 5 (C_s)

Figure 2. DFT B3LYP/6-31 G* optimized structures of **1**, **2**, and **5**.

Density Functional Theory (DFT)/IGLO Studies. To substantiate the observed experimental results we have calculated the structures and ¹³C and ²⁹Si NMR chemical shifts of tris(trimethylsilyl)sulfonium **1** and methylbis(trimethylsilyl)sulfonium **2**, as well as dimethyl(trimethylsilyl)sulfonium **5** ions. The structures were fully optimized at the density functional theory (DFT) B3LYP/6-31 G* level. The minimum energy structure of tris(trimethylsilyl)sulfonium ion was found to be of C₃ symmetry, as shown in Figure 2, with Si-S bond distance of 2.292 Å. The sulfur atom in **1** is modestly pyramidal.

(10) Abel, E. W.; Armitage, D. A.; Bush, R. P. *J. Chem. Soc.* **1964**, 2455.

(11) Franek, W.; El-Sayed, I. *Sulfur Lett.* **1996**, 19, 181.

(12) Reported ¹H NMR resonances (CDCl₃) are δ 0.18, 1.44, 2.85, 3.30. Yield 56%.

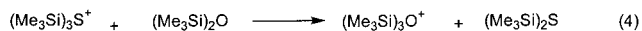
(13) Observed Me₃SiF has ¹H δ 0.22 (d, *J* = 7.8 Hz), ¹³C δ -0.1 (J = 15.1 Hz), ²⁹Si δ 34.3 (*J* = 273 Hz), ¹⁹F δ -156 ppm.

(14) Bassindale, A. R.; Stout, T. *Tetrahedron Lett.* **1984**, 25, 1631.

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The pyramidalization level is about 16°, expressed as the out-of-plane bending angle of the central sulfur atom relative to the plane defined by its three bonding partners. Optimized structures of methylbis(trimethylsilyl)sulfonium and dimethyl(trimethylsilyl)sulfonium ions were found to be of C_1 and C_s symmetry, respectively, with pyramidalization levels of 19° and 21° (Figure 2).

The relative stability of trisilylsulfonium and trisilyloxonium ions were compared by using the following isodesmic reaction (eq 4). Trimethylsilyl group transfer



from silylated sulfonium ion $(\text{Me}_3\text{Si})_3\text{S}^+$ **1** to $(\text{Me}_3\text{Si})_2\text{O}$ giving silylated oxonium ion $(\text{Me}_3\text{Si})_3\text{O}^+$ and $(\text{Me}_3\text{Si})_2\text{S}$ was computed to be endothermic by 11.8 kcal/mol. This again indicates that trialkylsulfonium ions are more stable than the corresponding trialkyloxonium ions. In comparison, the methyl group transfer from methylated sulfonium ion $(\text{CH}_3)_3\text{S}^+$ to $(\text{CH}_3)_2\text{O}$ giving methylated oxonium $(\text{CH}_3)_3\text{O}^+$ and $(\text{CH}_3)_2\text{S}$ was also calculated to be endothermic by 16.4 kcal/mol (eq 5).

We have also reproduced the ^{13}C and ^{29}Si NMR chemical shifts of **1** and **2** at the IGLO II//B3LYP/6-31G* level with reasonable degree of accuracy (Table 1). The calculated ^{29}Si δ of **1**, 42.9 ppm, agrees well with the experimental value of 38.8 ppm. The calculated ^{13}C δ of **1** is 3.0 ppm, also very close to the experimental value of 2.9 ppm. The calculated average ^{29}Si δ of **2** is 46.8 ppm, 6.0 ppm more deshielded than the experimental value of 40.8 ppm. On the other hand, the calculated average ^{13}C δ of Si-CH₃ in **2** is -0.3 ppm, close to the experimental value of -0.2 ppm. The ^{29}Si δ of **5** was computed to be 54.4 ppm.

Conclusions

The first silylsulfonium ions, tris(trimethylsilyl)sulfonium and methylbis(trimethylsilyl)sulfonium ions, were prepared as long-lived species and unequivocally characterized by ^1H , ^{13}C , and ^{29}Si NMR spectroscopy. The strong tendency for formation of the more stable trimethylsulfonium ion in solution has prevented successful

synthesis of the dimethylsilylsulfonium ion. The structural parameters and chemical shifts of the ions were also computed by DFT/IGLO methods. The calculated results agree reasonably well with the experimental data.

Experimental Section

Apparatus and Materials. Trimethylsilane (Gelest), hexamethyldisilathiane, methylthiotrimethylsilane, and CD_2Cl_2 (Aldrich) are commercially available and were used as received. Trityl tetrakis(pentafluorophenyl)borate (Ph_3C^+ TPF-PB) was prepared according to a literature method.¹⁶ All NMR spectra were obtained on a Varian 300 spectrometer equipped with a variable temperature probe, and chemical shifts (^1H , ^{13}C , and ^{29}Si) were referenced to tetramethylsilane.

Tris(trimethylsilyl)sulfonium Ion. Trimethylsilane (0.1 mL, ca. 0.8 mmol) was condensed in a 5 mm J. Young NMR tube and cooled to -78 °C in a dry ice/acetone bath. Hexamethyldisilathiane (0.24 mmol) and trityl TPF-PB (0.23 mmol) in CD_2Cl_2 (0.75 mL) were added subsequently to the NMR tube. The NMR tube sealed off at -78 °C, and the NMR spectra of the sample were recorded at -78 °C.

Methylbis(trimethylsilyl)sulfonium Ion. By using a similar procedure as described above, the reaction of trimethylsilane (0.1 mL) and methylthiotrimethylsilane (0.17 mmol) in the presence of 1 equiv of trityl TPF-PB (0.17 mmol) in CD_2Cl_2 at -78 °C gave a solution of methylbis(trimethylsilyl)sulfonium TPF-PB with triphenylmethane.

Calculation Methods, Basis Set, and Geometry. Calculations were carried out with the Gaussian 98 program system.¹⁷ The geometry optimizations were performed using the DFT¹⁸ method at the B3LYP¹⁹/6-31G* levels.²⁰ Vibrational frequencies at the B3LYP/6-31G**/B3LYP/6-31G* level were used to characterize stationary points as minima and to evaluate zero point vibrational energies (ZPE), which were scaled by a factor of 0.96. Isodesmic energies were calculated at the B3LYP/6-31G**/B3LYP/6-31G* + ZPE level. ^{13}C and ^{29}Si NMR calculations were performed according to the reported method using IGLO programs²¹ at the IGLO II' levels using B3LYP/6-31G* geometries. Huzinaga²² Gaussian lobes were used as follows. Basis II': Si, 11s 7p 2d contracted to [511111, 21111, 11], d exponent = 1.4 and 0.35; C, O: 9s 5p 1d contracted to [51111, 2111, 1], d exponent: 1.0; H: 3s contracted to [21]. The ^{13}C and ^{29}Si NMR chemical shifts were referenced to TMS (calculated absolute shift, i.e., $\delta(\text{Si}) = 380.6$ and $\delta(\text{C}) = 196.4$).

Acknowledgment. Partial support of our work by the National Science Foundation is gratefully acknowledged.

Supporting Information Available: ^1H , ^{13}C , and ^{29}Si NMR spectra of tris(trimethylsilyl)sulfonium and methylbis(trimethylsilyl)sulfonium ions at -78 °C and room temperature. This material is available free of charge via the Internet at <http://pubs.acs.org>.

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